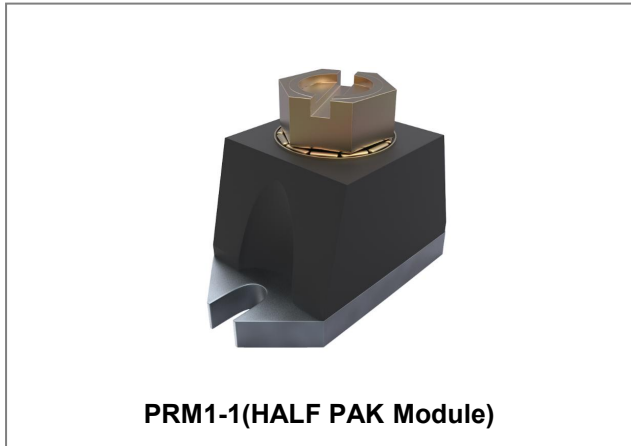


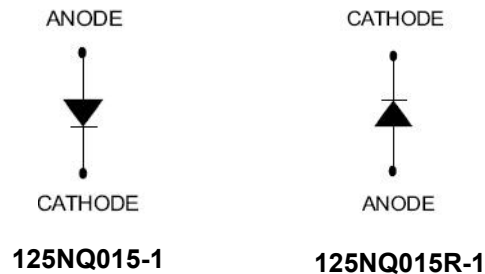
## 125NQ015/R-1 SCHOTTKY RECTIFIER



### Features

- 125°C T<sub>J</sub> operation
- Unique high power, Half-Pak module
- Replaces three parallel DO-5'S
- Easier to mount and lower profile than DO-5'S
- High purity, high temperature epoxy encapsulation for enhanced
- mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### Circuit Diagram



### Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

### Maximum Ratings:

| Characteristics  | Symbol   | Condition   | Max.                  | Units |
|--|--|---|-----------------------|-------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage | V <sub>RRM</sub><br>V <sub>RWM</sub><br>V <sub>R</sub> | -   | 15(DC)<br>25(Working) | V     |
| Average Forward Current  | I <sub>F(AV)</sub>                                     | 50% duty cycle @T <sub>C</sub> =71°C,<br>rectangular wave form  | 120                   | A     |
| Peak One Cycle Non-Repetitive Surge Current  | I <sub>FSM</sub>                                       | 8.3 ms, half Sine pulse   | 2040                  | A     |
| Non-Repetitive Avalanche Energy  | E <sub>AS</sub>  | T <sub>J</sub> =25°C, I <sub>AS</sub> =2A, L=4.5mH  | 9                     | mJ    |
| Repetitive Avalanche Current   | I <sub>AR</sub>  | Current decaying linearly to zero in 1<br>µsec Frequency limited by T <sub>J</sub> max.<br>V <sub>A</sub> =1.5×V <sub>R</sub> typical | 2                     | A     |

**Electrical Characteristics:**

| Characteristics        | Symbol   | Condition  | Typ. | Max.         | Units            |
|------------------------|----------|--|------|--------------|------------------|
| Forward Voltage Drop*  | $V_{F1}$ | @ 120A, Pulse, $T_J = 25\text{ }^\circ\text{C}$<br>@ 240A, Pulse, $T_J = 25\text{ }^\circ\text{C}$   | -    | 0.39<br>0.52 | V                |
|                        | $V_{F2}$ | @ 120A, Pulse, $T_J = 125\text{ }^\circ\text{C}$<br>@ 240A, Pulse, $T_J = 125\text{ }^\circ\text{C}$ | -    | 0.33<br>0.45 | V                |
| Reverse Current*       | $I_{R1}$ | @ $V_R = \text{rated } V_R, T_J = 25\text{ }^\circ\text{C}$  | 10   | 40           | mA               |
|                        | $I_{R2}$ | @ $V_R = \text{rated } V_R, T_J = 100\text{ }^\circ\text{C}$   | 1000 | 2000         | mA               |
|                        | $I_{R3}$ | @ $V_R = 12\text{V}, T_J = 100\text{ }^\circ\text{C}$  | 800  | 1780         | mA               |
|                        | $I_{R4}$ | @ $V_R = 5\text{V}, T_J = 100\text{ }^\circ\text{C}$   | 500  | 1080         | mA               |
| Junction Capacitance   | $C_T$    | @ $V_R = 5\text{V}, T_C = 25\text{ }^\circ\text{C}$<br>$f_{SIG} = 1\text{MHz}$                       | 6600 | 7700         | pF               |
| Voltage Rate of Change | dv/dt    | -  | -    | 10,000       | V/ $\mu\text{s}$ |

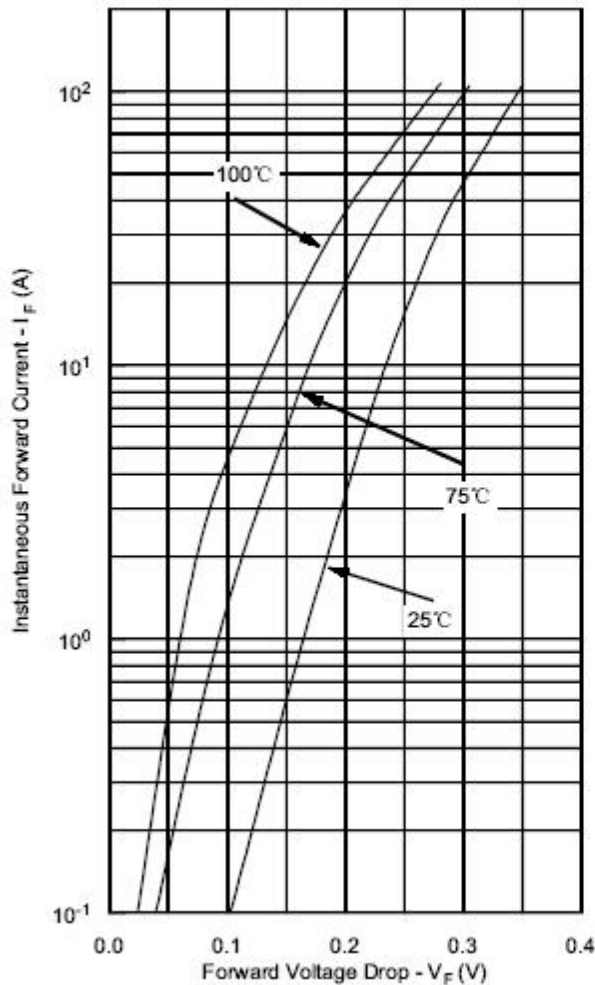
\* Pulse width < 300  $\mu\text{s}$ , duty cycle < 2%

**Thermal-Mechanical Specifications:**

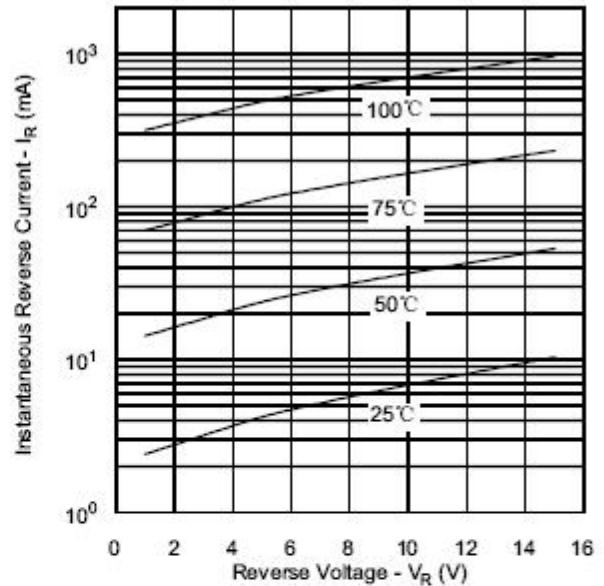
| Characteristics                                  | Symbol          | Condition                               | Specification      |                    | Units              |
|--|-----------------|---|--------------------|--------------------|--------------------|
| Junction Temperature                             | $T_J$           | -                                       | -55 to +125        |                    | $^\circ\text{C}$   |
| Storage Temperature                              | $T_{stg}$       | -                                       | -55 to +150        |                    | $^\circ\text{C}$   |
| Typical Thermal Resistance<br>Junction to Case   | $R_{\theta JC}$ | DC operation                            | 0.40               |                    | $^\circ\text{C/W}$ |
| Typical Thermal Resistance, case<br>to Heat Sink | $R_{\theta cs}$ | Mounting surface, smooth and<br>greased | 0.15               |                    | $^\circ\text{C/W}$ |
| Mounting Torque                                  | $T_M$           | Non-lubricated threads                  | Mounting<br>Torque | 23(min)<br>29(max) | Kg-cm              |
|  |                 |   | Terminal<br>Torque | 35(min)<br>46(max) |                    |
| Approximate Weight                               | wt              | -                                       | 25.6               |                    | g                  |
| Case Style                                       | PRM1-1          |   |                    |                    |                    |

**Ratings and Characteristics Curves**

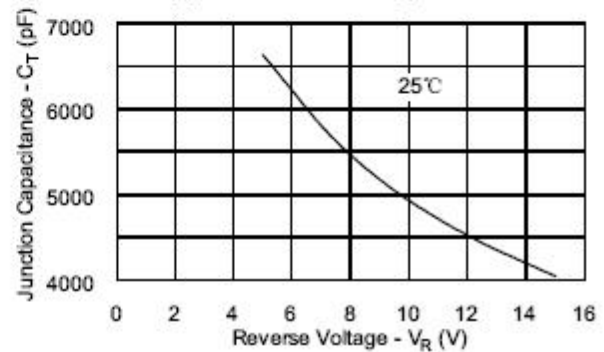
**Typical Forward Characteristics**



**Typical Reverse Characteristics**



**Typical Junction Capacitance**



**Ordering Information**

| Device        | Package         | Shipping   |
|---------------|-----------------|------------|
| 125NQ015(R)-1 | PRM1-1(Pb-Free) | 27pcs/ box |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

**Marking Diagram**

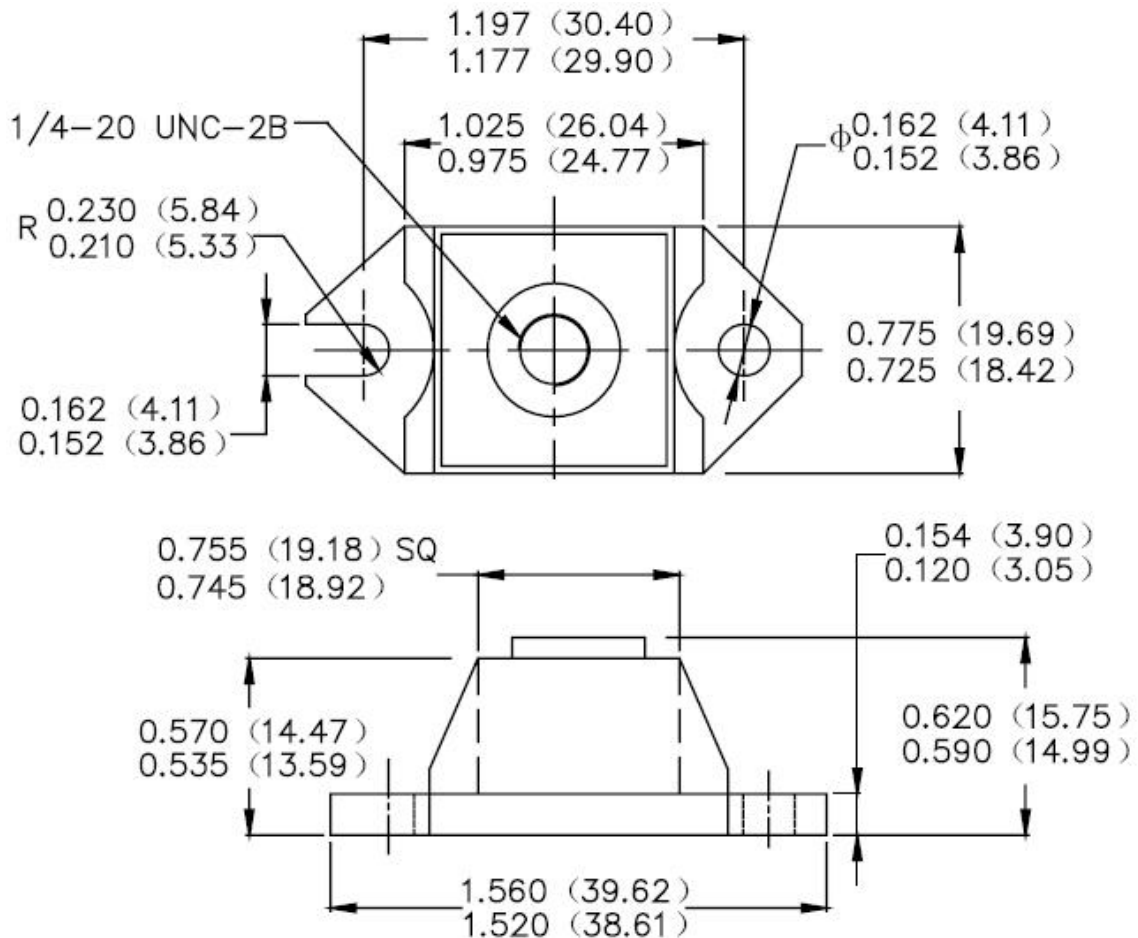


Where XXXX is YYWW

1st row SS YYWW  
2nd row 125NQ015-1  
SS = SS  
YY = Year  
WW = Week

**Cautions:** Molding resin  
Epoxy resin UL:94V-0

**Mechanical Dimensions PRM1-1 (Inches/Millimeters)**



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